

DESCRIPTION

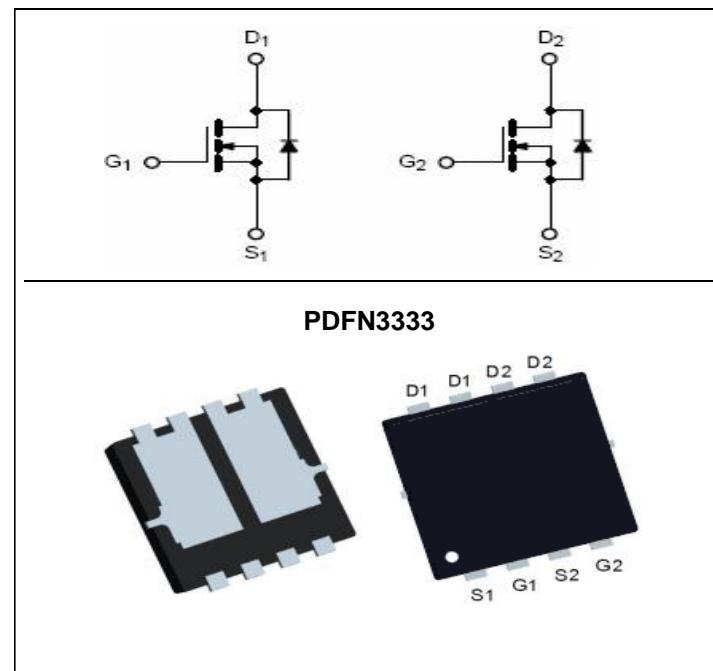
The 3622DE uses advanced trench technology to provide excellent RDS(ON) and low gate charge. This device is suitable for use as a load switch or in PWM applications.

GENERAL FEATURES

- RDS(ON) <10 mΩ @ VGS=10V
- RDS(ON) <13 mΩ @ VGS=4.5V
- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

Application

- PWM applications
- Load switch
- Power management



■ Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-source Voltage	V_{DS}	30	V
Gate-source Voltage	V_{GS}	± 20	V
Drain Current $T_C=25^\circ\text{C}$	I_D	35	A
$T_C=100^\circ\text{C}$		22	
Pulsed Drain Current ^A	I_{DM}	140	A
Total Power Dissipation $T_C=25^\circ\text{C}$	P_D	20	W
$T_C=100^\circ\text{C}$		15	W
Single Pulse Avalanche Energy ^B	E_{AS}	16	mJ
Thermal Resistance Junction-to-Case ^C	$R_{\theta JC}$	45	°C/W
Junction and Storage Temperature Range	T_J, T_{STG}	-55~+155	°C

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions		Min	Typ	Max	Units
Static Parameter							
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=250\mu\text{A}$		30			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}}=30\text{V}, V_{\text{GS}}=0\text{V}$	$T_J=25^\circ\text{C}$			1	μA
			$T_J=55^\circ\text{C}$			5	
Gate-Body Leakage Current	I_{GSS}	$V_{\text{GS}}=\pm 20\text{V}, V_{\text{DS}}=0\text{V}$				± 100	nA
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$		1.0	1.5	2.5	V
Static Drain-Source On-Resistance	$R_{\text{DS}(\text{ON})}$	$V_{\text{GS}}=10\text{V}, I_{\text{D}}=15\text{A}$			8.0	10	$\text{m}\Omega$
		$V_{\text{GS}}=4.5\text{V}, I_{\text{D}}=15\text{A}$			10	13	
Diode Forward Voltage	V_{SD}	$I_{\text{S}}=15\text{A}, V_{\text{GS}}=0\text{V}$			0.85	1.2	V
Maximum Body-Diode Continuous Current	I_{S}					30	A
Dynamic Parameters							
Input Capacitance	C_{iss}	$V_{\text{DS}}=15\text{V}, V_{\text{GS}}=0\text{V}, f=1\text{MHz}$			1020		pF
Output Capacitance	C_{oss}				225		
Reverse Transfer Capacitance	C_{rss}				126		
Switching Parameters							
Total Gate Charge	Q_{g}	$V_{\text{GS}}=10\text{V}, V_{\text{DS}}=15\text{V}, I_{\text{D}}=30\text{A}$			28		nC
Gate-Source Charge	Q_{gs}				7		
Gate-Drain Charge	Q_{gd}				5		
Reverse Recovery Charge	Q_{rr}	$I_{\text{F}}=15\text{A}, dI/dt=100\text{A/us}$			25		ns
Reverse Recovery Time	t_{rr}				26		
Turn-on Delay Time	$t_{\text{D(on)}}$				8		
Turn-on Rise Time	t_{tr}	$V_{\text{GS}}=10\text{V}, V_{\text{DD}}=20\text{V}, I_{\text{D}}=2\text{A}, R_{\text{L}}=1\Omega, R_{\text{GEN}}=3\Omega$			15		
Turn-off Delay Time	$t_{\text{D(off)}}$				27		
Turn-off fall Time	t_{tf}				7		

A. Pulse Test: Pulse Width $\leq 300\text{us}$, Duty cycle $\leq 2\%$.B. $T_J=25^\circ\text{C}$, $V_{\text{DD}}=20\text{V}$, $V_{\text{G}}=10\text{V}$, $L=0.5\text{mH}$, $R_g=25\Omega$ C. R_{gJA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{gJC} is guaranteed by design, while R_{gJA} is determined by the board design. The maximum rating present elsewhere is based on mounting on a 1 in 2 pad of 2oz copper.

■ Typical Performance Characteristics

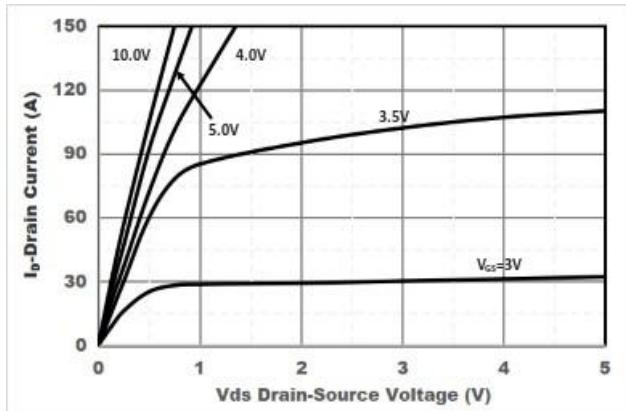


Figure1. Output Characteristics

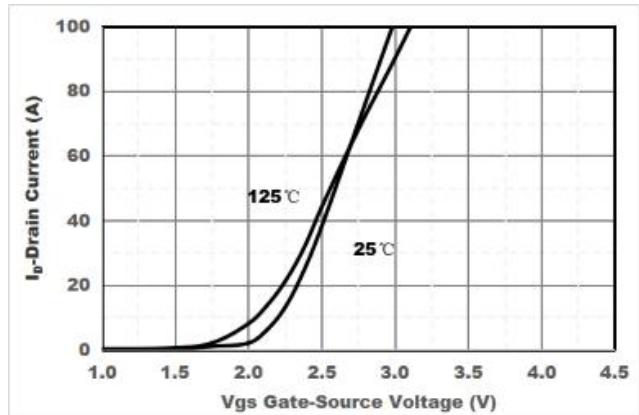


Figure2. Transfer Characteristics

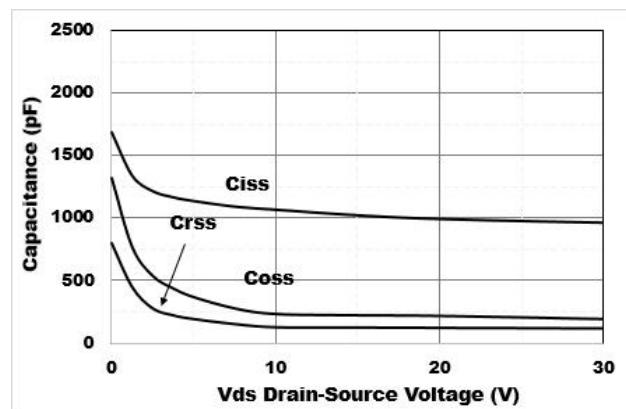


Figure3. Capacitance Characteristics

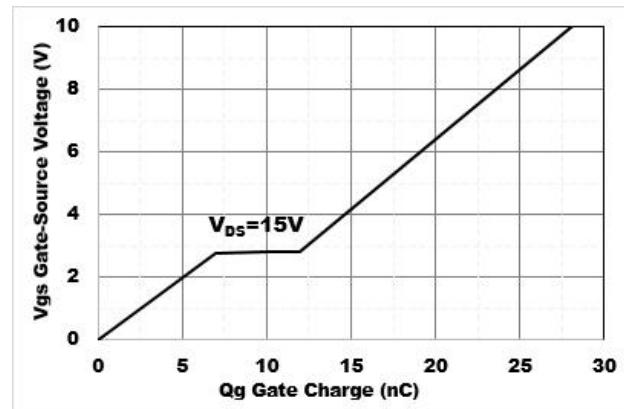


Figure4. Gate Charge

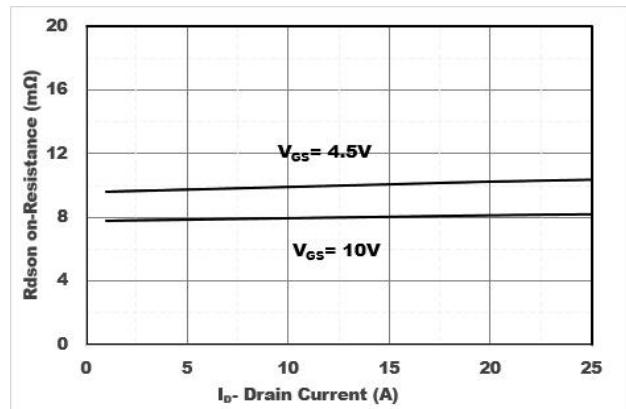


Figure5. Drain-Source on Resistance

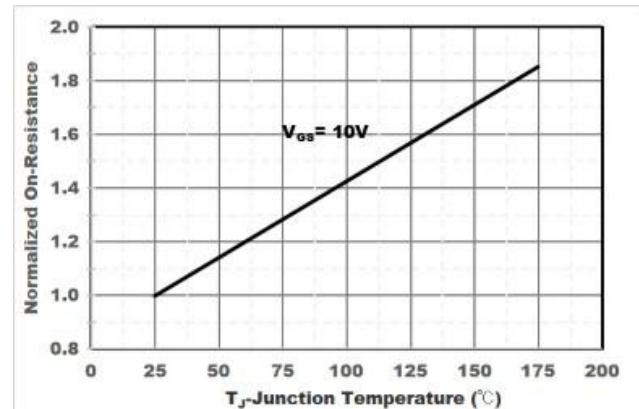


Figure6. Drain-Source on Resistance

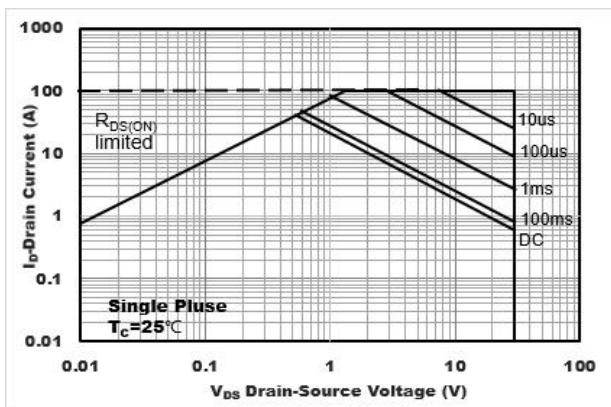


Figure 7. Safe Operation Area

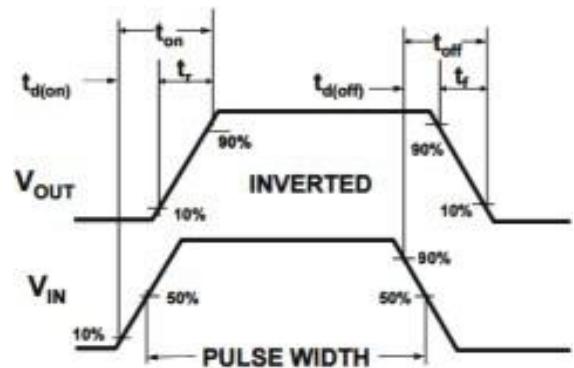
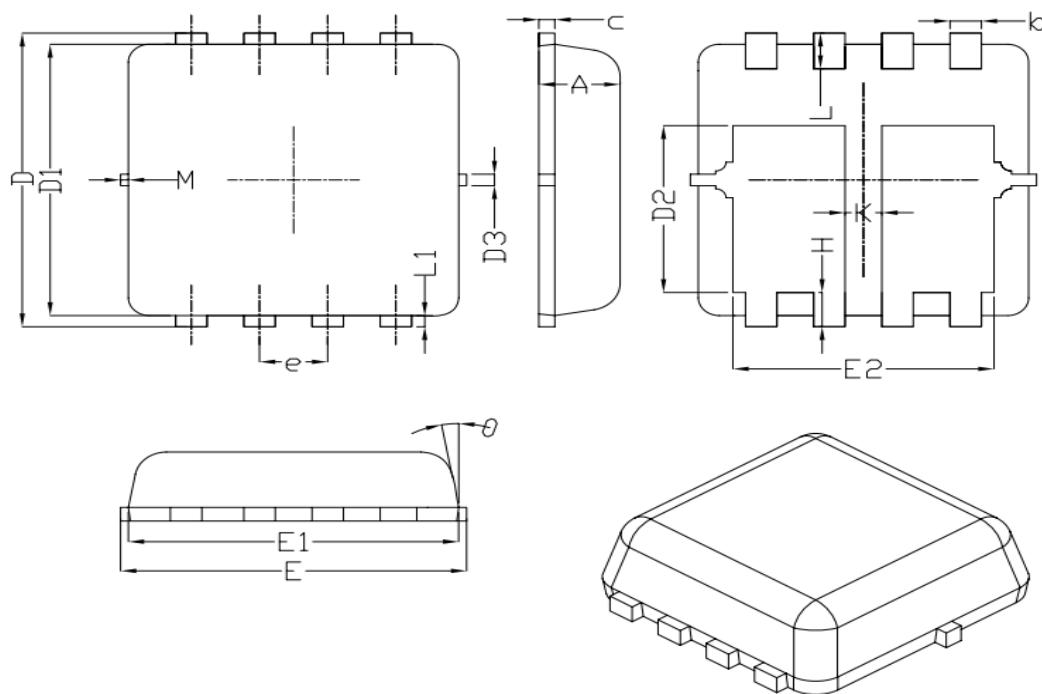


Figure 8. Switching wave

Package Information



Symbol	Dimensions (unit: mm)		
	Min	Typ	Max
A	0.70	0.75	0.80
b	0.25	0.30	0.35
c	0.10	0.15	0.25
D	3.25	3.35	3.45
D1	3.00	3.10	3.20
D2	1.78	1.88	1.98
D3	--	0.13	--
E	3.20	3.30	3.40
E1	3.00	3.15	3.20
E2	2.39	2.49	2.59
e	0.65 BSC		
H	0.30	0.39	0.50
L	0.30	0.40	0.50
L1	--	0.13	--
K	0.30	--	--
θ	--	10°	12°
M	*	*	0.15
* Not Specified			